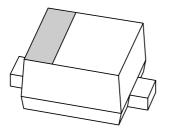
DISCRETE SEMICONDUCTORS

DATA SHEET



1PS79SB31 Schottky barrier diode

Product specification

2002 Jan 11





Schottky barrier diode

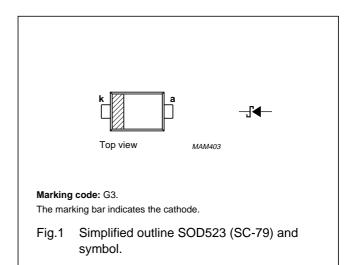
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FEATURES

- Very low forward voltage
- · Guard ring protected
- Ultra small SMD package.

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- · Low current rectification
- Low power consumption applications (e.g. hand-held devices).



DESCRIPTION

Planar Schottky barrier diode in a SOD523 (SC-79) ultra small SMD plastic package.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	30	V
I _F	continuous forward current		_	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	300	mA
I _{FSM}	non-repetitive peak forward current	t = 8.3 ms half sine wave; JEDEC method	_	1000	mA
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	125	°C
T _{amb}	operating ambient temperature		-65	+125	°C

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	see Fig.2;			
		I _F = 0.1 mA	130	190	mV
		I _F = 1 mA	190	250	mV
		I _F = 10 mA	255	300	mV
		I _F = 100 mA	355	410	mV
		I _F = 200 mA	420	500	mV
I _R	continuous reverse current	V _R = 10 V; note 1; see Fig.3	2.5	30	μΑ
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; see Fig.4	20	25	pF

Note

1. Pulse test: t_p = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	450	K/W

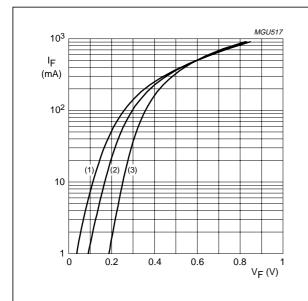
Note

1. Refer to SC-79 (SOD523) standard mounting conditions.

Schottky barrier diode

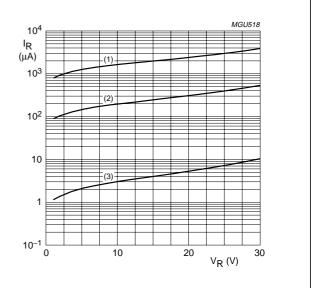
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GRAPHICAL DATA



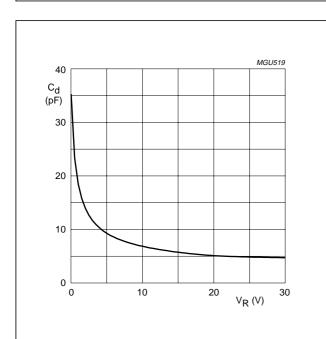
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.



(1) f = 1 MHz; $T_{amb} = 25 \,^{\circ}\text{C}$.

Fig.4 Diode capacitance as a function of reverse voltage; typical values.

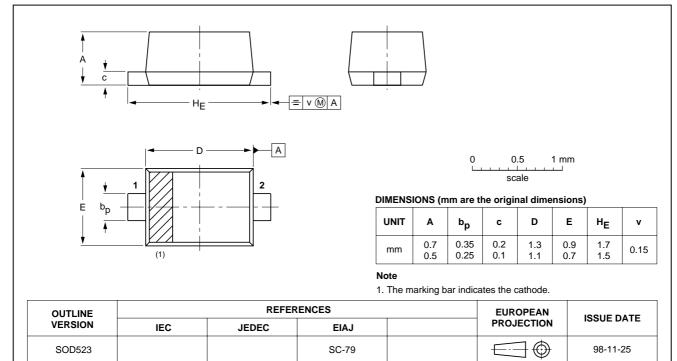
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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD523



Schottky barrier diode

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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